EUV mask-related inspection systems Lineup

We embarked on the development of high-performance inspection systems for EUV lithography early on and have diligently devoted time and effort to acquire technical expertise in the area of EUV mask inspection. We have 6 products in our lineup today to meet customer needs.



Leading-edge semiconductor devices and EUV

Semiconductor devices need to introduce finer and more complex IC designs to enjoy the merit of scaling and achieve better performance. Major device manufacturers have started using EUV lithography in volume production to print finer patterns on semiconductor chips since 2019. EUV lithography is a critical technology for manufacturing leading-edge semiconductors to enable the 5th generation mobile communication (5G), artificial intelligence (AI) and other innovations. The application of EUV lithography to semiconductor production is expected to grow rapidly.



Growing demand for semiconductor devices

Logic devices for calculation and image processing

Memories for data storage

Image sensors for light sensing and imaging

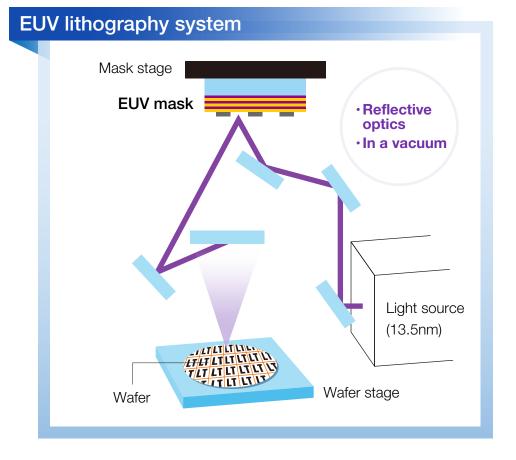
Power devices for optimal power conversion and control

As semiconductor devices attain a higher level of scaling and performance, inspection with better tools will be required.

What is EUV lithography?

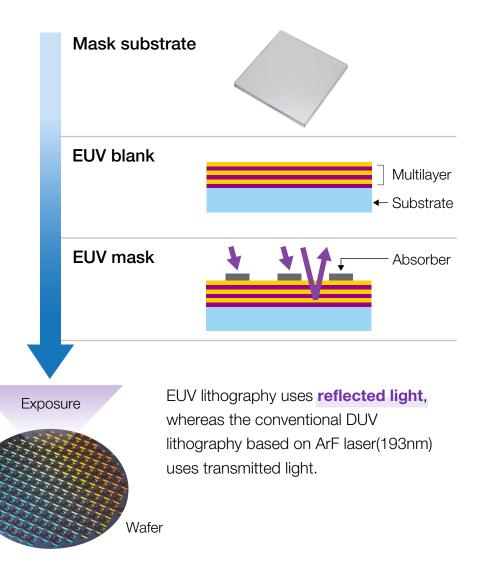
EUV lithography is a type of lithography using the extreme ultraviolet (EUV) range of light. It is capable of creating much finer IC patterns than previously possible because its wavelength (13.5nm) is much shorter than that of the ArF excimer laser (193nm) used in conventional DUV lithography.

Lithography is a technique to form patterns (e.g., line and space) on silicon wafers, which are eventually diced to make semiconductor chips. In lithography, wafers are exposed to light projected via a photomask, which is a plate with the blueprint of a pattern, after a photosensitive chemical called photoresist is applied on them. The pattern appears on the exposed wafers when the photoresist is removed from them. Multiple photomasks with different patterns are used to form an integrated circuit.

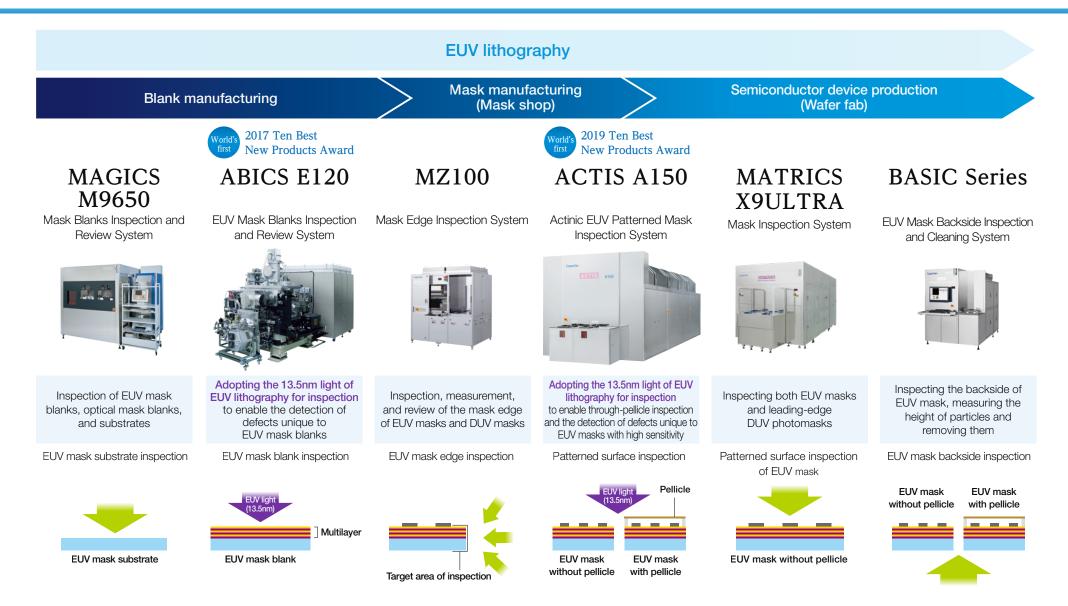


EUV: Extreme ultraviolet, which is a range of the wavelengths of light around 13.5nm, less than 1/10 the wavelength used in conventional lithography

EUV lithography: Leading-edge lithography using EUV light to enable the further scaling of semiconductor devices to achieve the design nodes of 5nm and beyond



Lineup of EUV-related systems from Lasertec



Pellicle: Protective film designed to prevent patterned surface from being contaminated with particles

Lasertec is offering solutions to the customer's challenges by providing advanced inspection and measurement systems based on applied optical technologies, thereby contributing to society.